NSN 5961-01-038-2061

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-038-2061 **Inclosure Material:** Plastic **Overall Length:** Between 0.120 inches and 0.240 inches **Terminal Length:** 0.500 inches **Overall Width:** 0.222 inches **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 50.0 on voltage, forward voltage drop, dc **Current Rating Per Characteristic:** 20.00 milliamperes source cutoff current preset and 50.00 milliamperes forward current, average peak **Power Rating Per Characteristic:** 350.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius ambient air **Test Data Document:** 89536-348482 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No